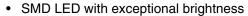




Bicolor SMD LED PLCC-3

FEATURES





- Multicolored
- · Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with IR reflow, vapor phase and wave soldering processes according to CECC 00802 and J-STD-020-C
- · Available in 8 mm tape
- · Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \le 2.0$
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- · Lead (Pb)-free device
- · Preconditioning: acc. to JEDEC level 2a
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B

APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- · Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- · General use



DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the VLMV3100 is the PLCC-3.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

This SMD device consists of a red and green chip. So it is possible to choose the color in one device.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED
Package: SMD PLCC-3
Product series: bicolor
Angle of half intensity: ± 60°

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMV3100-GS08	Green/red, $I_V > 2.8 \text{ mcd}$	GaP on GaP/GaAsP on GaP
VLMV3100-GS18	Green/red, I _V > 2.8 mcd	GaP on GaP/GaAsP on GaP

VLMV3100

Vishay Semiconductors



ABSOLUTE MAXIMUM RATINGS ¹⁾ VLMV3100					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage per diode ²⁾	I _R = 10 μA	V_{R}	6	V	
DC Forward current per diode	T _{amb} ≤ 60 °C	I _F	30	mA	
Surge forward current per diode	t _p ≤ 10 μs	I _{FSM}	0.5	Α	
Power dissipation per diode		P _V	100	mW	
Junction temperature		T _j	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	400	K/W	

Note:

 ¹⁾ T_{amb} = 25 °C unless otherwise specified
 2) Driving the LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLMV3100, RED						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity ²⁾	I _F = 10 mA	I _V	2.8	6		mcd
Dominant wavelength	I _F = 10 mA	λ_{d}	612		625	nm
Peak wavelength	I _F = 10 mA	λρ		635		nm
Angle of half intensity	I _F = 10 mA	φ		± 60		deg
Forward voltage per diode	I _F = 20 mA	V _F		2.4	3	V
Reverse current per diode	V _R = 6 V	I _R			10	μΑ
Junction capacitance per diode	V _R = 0, f = 1 MHz	C _j		15		pF

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLMV3100, GREEN						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity ²⁾	I _F = 10 mA	I _V	2.8	6		mcd
Dominant wavelength	I _F = 10 mA	λ _d	562		575	nm
Peak wavelength	I _F = 10 mA	λ_{p}		565		nm
Angle of half intensity	I _F = 10 mA	φ		± 60		deg
Forward voltage per diode	I _F = 20 mA	V _F		2.4	3	V
Reverse current per diode	V _R = 6 V	I _R			10	μΑ
Junction capacitance per diode	V _R = 0, f = 1 MHz	C _j		15		pF

Note:

¹⁾ T_{amb} = 25 °C unless otherwise specified 2) in one packing unit $I_{Vmax}/I_{Vmin} \le 0.5$

⁽¹⁾ $T_{amb} = 25$ °C unless otherwise specified ⁽²⁾ in one Packing Unit $I_{Vmax}/I_{Vmin} \le 0.5$



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COLOR CLASSIFICATION					
GROUP	GREEN				
	DOM. WAVELENGTH [NM]				
	MIN. MAX.				
3	562	565			
4	564	567			
5	566	569			
6	568	571			
7	570	573			
8	572	575			

Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of \pm 1 nm.

LUMINOUS INTENSITY CLASSIFICATION					
GROUP	LIGHT INTENSITY [MCD]				
STANDARD	OPTIONAL	MAX			
Н	1	2.8	3.55		
""	2	3.55	4.5		
J	1	4.5	5.6		
٦	2	5.6	7.1		
К	1	7.1	9.0		
IX.	2	9.0	11.2		
1	1	11.2	14.0		
L	2	14.0	18.0		
М	1	18.0	22.4		
	2	22.4	28.0		

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above Type Numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

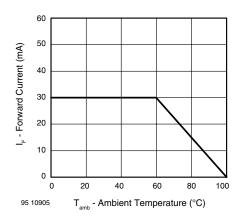


Figure 1. Forward Current vs. Ambient Temperature

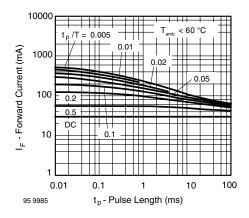
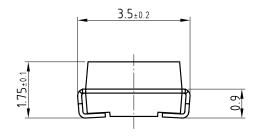


Figure 2. Pulse Forward Current vs. Pulse Duration

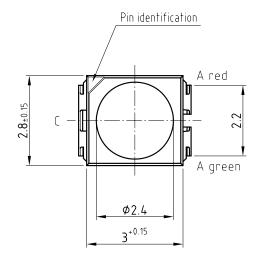
Vishay Semiconductors

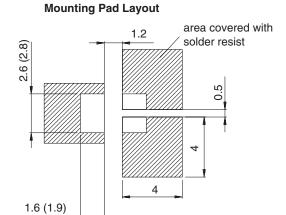
VISHAY.

PACKAGE DIMENSIONS









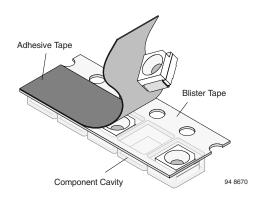
Dimensions: IR and Vaporphase (Wave Soldering)

Drawing-No.: 6.541-5068.01-4 Issue: 2; 30.05.07

METHOD OF TAPING/POLARITY AND TAPE AND REEL

SMD LED (VLM.3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLM.3...

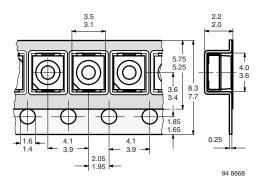


Figure 14. Tape Dimensions in mm for PLCC-2